74HC4017; 74HCT4017

Johnson decade counter with 10 decoded outputs Rev. 03 — 8 January 2008 Produ

Product data sheet

1. **General description**

The 74HC4017; 74HCT4017 is a high-speed Si-gate CMOS device and is pin compatible with the HEF4017.

The 74HC4017; 74HCT4017 is a 5-stage Johnson decade counter with 10 decoded active HIGH outputs (Q0 to Q9), an active LOW output from the most significant flip-flop (\overline{Q} 5-9), active HIGH and active LOW clock inputs (CP0 and CP1) and an overriding asynchronous master reset input (MR).

The counter is advanced by either a LOW-to-HIGH transition at CP0 while CP1 is LOW or a HIGH-to-LOW transition at $\overline{CP}1$ while CP0 is HIGH (see Table 3).

When cascading counters, the $\overline{Q}5$ -9 output, which is LOW while the counter is in states 5, 6, 7, 8 and 9, can be used to drive the CP0 input of the next counter.

A HIGH on MR resets the counter to zero (Q0 = \overline{Q} 5-9 = HIGH; Q1 to Q9 = LOW) independent of the clock inputs (CP0 and $\overline{CP1}$).

Automatic code correction of the counter is provided by an internal circuit: following any illegal code the counter returns to a proper counting mode within 11 clock pulses.

Features 2.

- Multiple package options
- Complies with JEDEC standard no. 7 A
- ESD protection:
 - HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

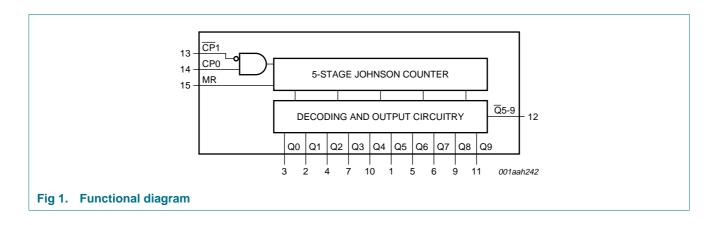


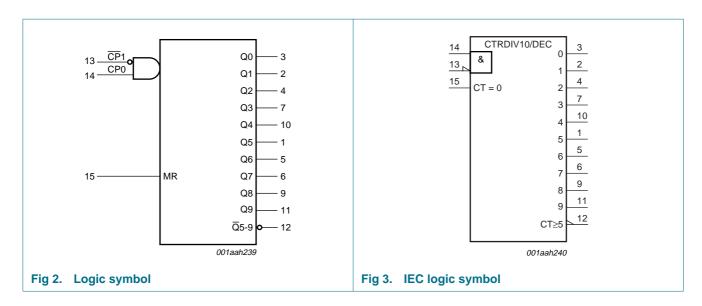
3. Ordering information

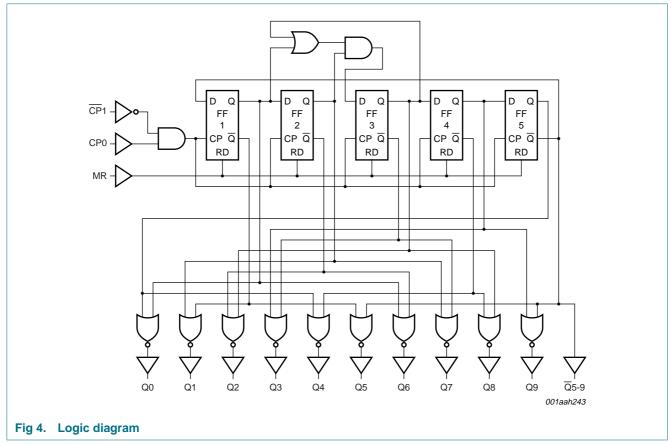
Table 1. Ordering information

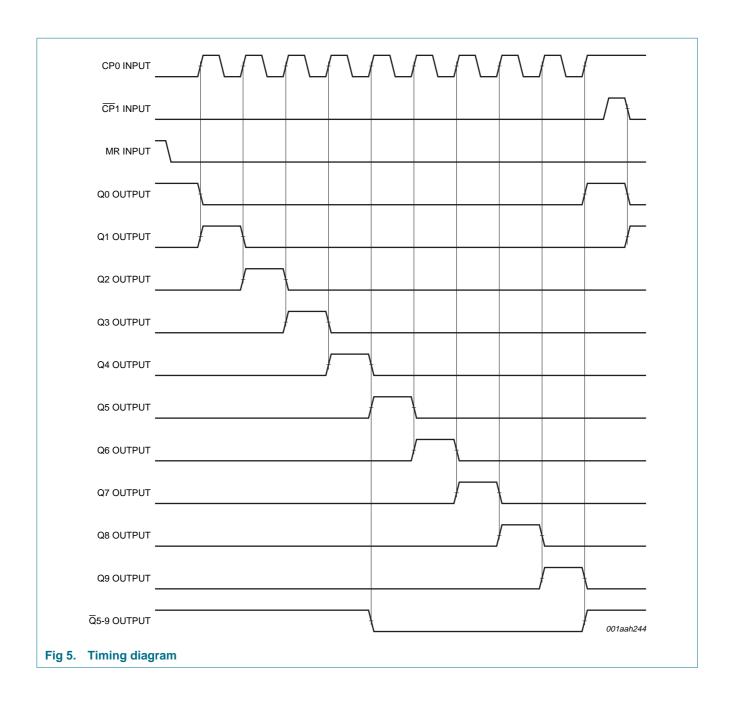
Type number	Package			
	Temperature range	Name	Description	Version
74HC4017				
74HC4017N	–40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4
74HC4017D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HC4017DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1
74HC4017PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74HC4017BQ	–40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal-enhanced very thin quad flat package; no leads; 16 terminals; body $2.5\times3.5\times0.85$ mm	SOT763-1
74HCT4017				
74HCT4017N	–40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4
74HCT4017D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HCT4017BQ	–40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal-enhanced very thin quad flat package; no leads; 16 terminals; body $2.5\times3.5\times0.85$ mm	SOT763-1

4. Functional diagram



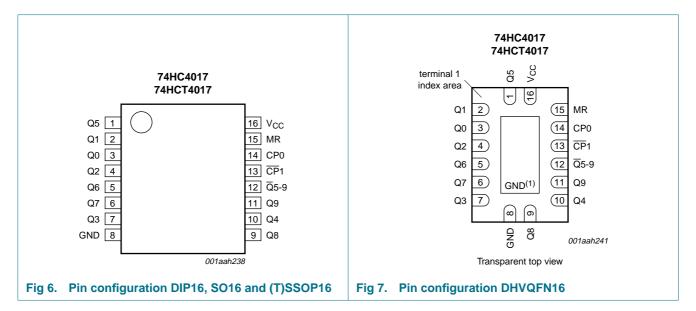






5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
Q[0:9]	3, 2, 4, 7, 10, 1, 5, 6, 9, 11	decoded output
GND	8	ground (0 V)
Q 5-9	12	carry output (active LOW)
CP1	13	clock input (HIGH-to-LOW edge-triggered)
CP0	14	clock input (LOW-to-HIGH edge-triggered)
MR	15	master reset input (active HIGH)
V _{CC}	16	supply voltage

6. Functional description

Table 3. Function table^[1]

MR	CP0	CP1	Operation
Н	X	X	Q0 = \overline{Q} 5-9 = HIGH; Q1 to Q9 = LOW
L	Н	\downarrow	counter advances
L	↑	L	counter advances
L	L	X	no change
L	X	Н	no change
L	Н	↑	no change
L	\downarrow	L	no change

^[1] H = HIGH voltage level;

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> _	±20	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> _	±20	mA
Io	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I _{CC}	supply current		-	50	mA
I_{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$			
	DIP16 package		[2] _	750	mW
	SO16 package		[3] _	500	mW
	(T)SSOP16 package		<u>[4]</u> _	500	mW
	DHVQFN16 package		<u>[5]</u> _	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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L = LOW voltage level;

X = don't care;

^{↑ =} LOW-to-HIGH transition;

 $[\]downarrow$ = HIGH-to-LOW transition;

^[2] P_{tot} derates linearly with 12 mW/K above 70 °C.

^[3] P_{tot} derates linearly with 8 mW/K above 70 °C.

^[4] P_{tot} derates linearly with 5.5 mW/K above 60 °C.

^[5] P_{tot} derates linearly with 4.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
74HC4017						
V_{CC}	supply voltage		2.0	5.0	6.0	V
V_{I}	input voltage		0	-	V_{CC}	V
V_{O}	output voltage		0	-	V_{CC}	V
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 2.0 \text{ V}$	-	-	625	ns/V
		$V_{CC} = 4.5 \text{ V}$	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	ns/V
T _{amb}	ambient temperature		-40	-	+125	°C
74HCT4017						
V_{CC}	supply voltage		4.5	5.0	5.5	V
V_{I}	input voltage		0	-	V_{CC}	V
V_{O}	output voltage		0	-	V_{CC}	V
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 4.5 \text{ V}$	-	1.67	139	ns/V
T _{amb}	ambient temperature		-40	-	+125	°C

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C to	+85 °C	-40 °C to +125 °C		Unit
				Тур	Max	Min	Max	Min	Max	
74HC40	17	'								
V_{IH}	V _{IH} HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
		V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL} LOW-level	V _{CC} = 2.0 V	-	8.0	0.5	-	0.5	-	0.5	V	
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V_{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	3.84	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	5.34	-	5.2	-	V

Product data sheet

Johnson decade counter with 10 decoded outputs

Table 6. Static characteristics ... continued At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}				1				
	output voltage	$I_O = 20 \mu A; V_{CC} = 2.0 \text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
C _I	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT4	017									
V_{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	1.6	-	2.0	-	2.0	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	1.2	0.8	-	8.0	-	0.8	V
V_{OH}		$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_{O} = -20 \mu A$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -4 \text{ mA}$	3.98	4.32	-	3.84	-	3.7	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_O = 20 \mu A$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 4.0 \text{ mA}$	-	0.15	0.26	-	0.33	-	0.4	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $I_O = 0$ A	-	-	8.0	-	80	-	160	μΑ
ΔI_{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V};$ other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $I_O = 0 \text{ A}$								
		CP0 input	-	25	90	-	113	-	123	μΑ
		CP1 input	-	40	144	-	180	-	196	μΑ
		MR input	-	50	180	-	225	-	245	μΑ
C _I	input capacitance		-	3.5	-	-	-	-	-	pF

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10. Dynamic characteristics

Table 7. Dynamic characteristics

 $GND = 0 \text{ V; } t_r = t_f = 6 \text{ ns; } C_L = 50 \text{ pF; see Figure 11.}$

Symbol	Parameter	Conditions			25 °C		–40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	
74HC40	17		ľ		•						
t _{pd}	propagation delay	CP0 to Qn; CP0 to $\overline{Q}5-9$; see Figure 10	[1]								
		V _{CC} = 2.0 V		-	63	230	-	290	-	345	ns
		V _{CC} = 4.5 V		-	23	46	-	58	-	69	ns
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$		-	20	-	-	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$		-	18	39	-	49	-	59	ns
		$\overline{\text{CP}}$ 1 to Qn; $\overline{\text{CP}}$ 1 to $\overline{\text{Q}}$ 5-9; see Figure 10									
		V _{CC} = 2.0 V		-	61	250	-	315	-	375	ns
		V _{CC} = 4.5 V		-	22	50	-	63	-	75	ns
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$		-	20	-	-	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$		-	18	43	-	54	-	64	ns
t _{PHL}	HIGH to LOW propagation	MR to Q[1:9]; see Figure 10									
	delay	$V_{CC} = 2.0 \text{ V}$		-	52	230	-	290	-	345	ns
		$V_{CC} = 4.5 \text{ V}$		-	19	46	-	58	-	69	ns
		$V_{CC} = 6.0 \text{ V}$		-	15	39	-	49	-	59	ns
t _{PLH}	LOW to HIGH propagation	MR to \overline{Q} 5-9, Q0; see Figure 10									
	delay	V_{CC} = 2.0 V		-	55	230	-	290	-	345	ns
		$V_{CC} = 4.5 \text{ V}$		-	20	46	-	58	-	69	ns
		$V_{CC} = 6.0 \text{ V}$		-	16	39	-	49	-	59	ns
t _t	transition time	see Figure 10	[2]								
		$V_{CC} = 2.0 \text{ V}$		-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5 \text{ V}$		-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 \text{ V}$		-	6	13	-	16	-	19	ns
t_W	pulse width	CP0 and CP1 (HIGH or LOW); see Figure 9									
		V_{CC} = 2.0 V		80	17	-	100	-	120	-	ns
		$V_{CC} = 4.5 \text{ V}$		16	6	-	20	-	24	-	ns
		$V_{CC} = 6.0 \text{ V}$		14	5	-	17	-	20	-	ns
		MR (HIGH); see Figure 9									
		$V_{CC} = 2.0 \text{ V}$		80	19	-	100	-	120	-	ns
		$V_{CC} = 4.5 \text{ V}$		16	7	-	20	-	24	-	ns
		$V_{CC} = 6.0 \text{ V}$		14	6	-	17	-	20	-	ns

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Table 7. Dynamic characteristics ...continued GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; see Figure 11.

Symbol	Parameter	Conditions		25 °	С	-40 °C 1	to +85 °C	-40 °C to +125 °C		Unit
			Mi	n Typ	Max	Min	Max	Min	Max	
t _{su}	set-up time	CP1 to CP0; CP0 to CP1; see Figure 8								
		$V_{CC} = 2.0 \text{ V}$	50	0 –8	-	65	-	75	-	ns
		$V_{CC} = 4.5 \text{ V}$	10) –3	-	13	-	15	-	ns
		$V_{CC} = 6.0 \text{ V}$	9	-2	-	11	-	13	-	ns
t _h	hold time	CP1 to CP0; CP0 to CP1; see Figure 8								
		$V_{CC} = 2.0 \text{ V}$	50) 17	-	65	-	75	-	ns
		$V_{CC} = 4.5 \text{ V}$	10	6	-	13	-	15	-	ns
		$V_{CC} = 6.0 \text{ V}$	9	5	-	11	-	13	-	ns
t _{rec}	recovery time	MR to CP0 and MR to CP1; see Figure 9								
		$V_{CC} = 2.0 \text{ V}$	5	-17	-	5	-	5	-	ns
		$V_{CC} = 4.5 V$	5	-6	-	5	-	5	-	ns
		$V_{CC} = 6.0 \text{ V}$	5	-5	-	5	-	5	-	ns
f _{max} maximum		CP0 or $\overline{\text{CP}}1$; see Figure 9								
	frequency	$V_{CC} = 2.0 \text{ V}$	6.	0 23	-	4.8	-	4.0	-	МН
		$V_{CC} = 4.5 \text{ V}$	30	70	-	24	-	20	-	МН
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$	-	77	-	-	-	-	-	MH
		$V_{CC} = 6.0 \text{ V}$	2	5 83	-	28	-	24	-	MH
C_PD	power dissipation capacitance	$V_I = GND \text{ to } V_{CC};$ $V_{CC} = 5 \text{ V}; f_i = 1 \text{ MHz}$	[3] -	35	-	-	-	-	-	pF
74HCT4	017									
t _{pd}	propagation delay	CP0 to Qn; CP0 to \overline{Q} 5-9; see Figure 10	<u>[1]</u>							
		$V_{CC} = 4.5 V$	-	25	46	-	58	-	69	ns
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$	-	21	-	-	-	-	-	ns
		$\overline{\text{CP}}$ 1 to Qn; $\overline{\text{CP}}$ 1 to $\overline{\text{Q}}$ 5-9; see Figure 10								
		$V_{CC} = 4.5 \text{ V}$	-	25	50	-	63	-	75	ns
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$	-	21	-	-	-	-	-	ns
t _{PHL}	HIGH to LOW propagation	MR to Q[1:9]; see Figure 10								
	delay	$V_{CC} = 4.5 \text{ V}$	-	22	46	-	58	-	69	ns
t _{PLH}	LOW to HIGH propagation	MR to $\overline{Q}5-9$, Q0; see Figure 10								
	delay	V _{CC} = 4.5 V	-	20	46	-	58	-	69	ns

Table 7. Dynamic characteristics ...continued GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; see Figure 11.

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
t _t	transition time	see Figure 10 [2]					'			
		$V_{CC} = 4.5 \text{ V}$	-	7	15	-	19	-	22	ns
t _W pulse width		CP0 and CP1 (HIGH or LOW); see Figure 9								
		$V_{CC} = 4.5 \text{ V}$	16	7	-	20	-	24	-	ns
		MR (HIGH); see Figure 9								
		$V_{CC} = 4.5 \text{ V}$	16	4	-	20	-	24	-	ns
t _{su}	set-up time	CP1 to CP0; CP0 to CP1; see Figure 8								
		$V_{CC} = 4.5 \text{ V}$	10	-3	-	13	-	15	-	ns
t _h	hold time	CP1 to CP0; CP0 to CP1; see Figure 8								
		$V_{CC} = 4.5 \text{ V}$	10	6	-	13	-	15	-	ns
t _{rec}	recovery time	MR to CP0 and MR to CP1; see Figure 9								
		$V_{CC} = 4.5 \text{ V}$	5	-5	-	5	-	5	-	ns
f _{max}	maximum	CP0 or CP1; see Figure 9								
	frequency	$V_{CC} = 4.5 \text{ V}$	30	61	-	24	-	20	-	MHz
		$V_{CC} = 5.0 \text{ V};$ $C_{L} = 15 \text{ pF}$	-	67	-	-	-	-	-	MHz
C_{PD}	power dissipation capacitance	$V_{I} = GND \text{ to } V_{CC} - 1.5 \text{ V};$ [3] $V_{CC} = 5 \text{ V}; f_{i} = 1 \text{ MHz}$	-	36	-	-	-	-	-	pF

^[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

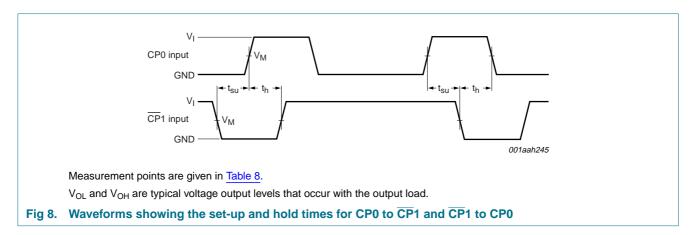
N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

^[2] t_t is the same as t_{THL} and t_{TLH} .

^[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

11. Waveforms



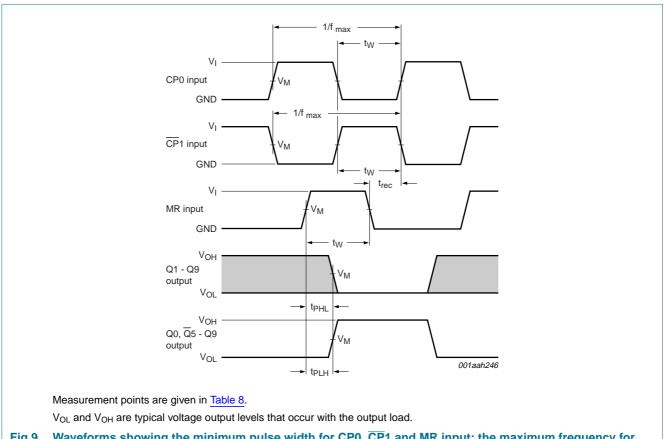
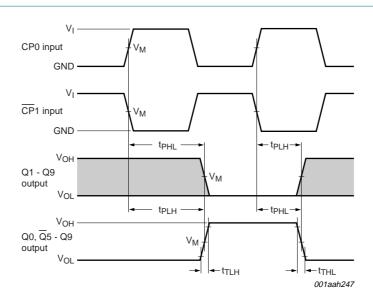


Fig 9. Waveforms showing the minimum pulse width for CP0, $\overline{\text{CP}1}$ and MR input; the maximum frequency for CP0 and $\overline{\text{CP}1}$ input; the recovery time for MR and the MR input to Qn and $\overline{\text{Q}5}$ -9 output propagation delays



Measurement points are given in Table 8.

 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Conditions: $\overline{\text{CP}}1 = \text{LOW}$ while CP0 is triggered on a LOW-to-HIGH transition and CP0 = HIGH, while $\overline{\text{CP}}1$ is triggered on a HIGH-to-LOW transition.

Fig 10. Waveforms showing the propagation delays for CP0, $\overline{\text{CP}}1$ to Qn, $\overline{\text{Q}}5$ -9 outputs and the output transition times

Table 8. Measurement points

Туре	Input	Output
	V _M	V _M
74HC4017	0.5 × V _{CC}	$0.5 \times V_{CC}$
74HCT4017	1.3 V	1.3 V

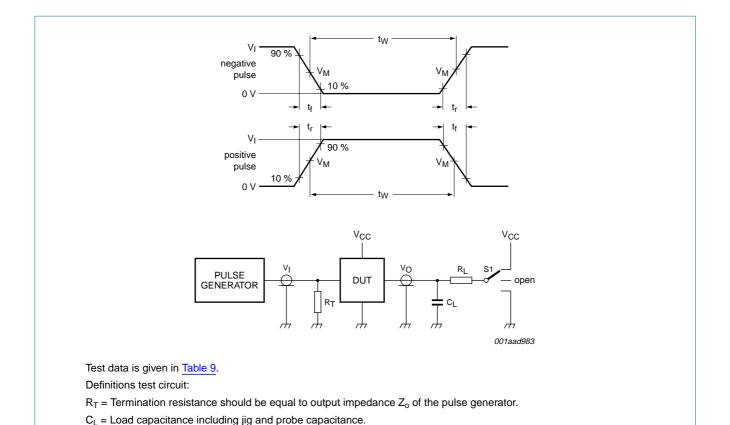


Fig 11. Load circuitry for measuring switching times

Table 9. Test data

R_L = Load resistance.S1 = Test selection switch.

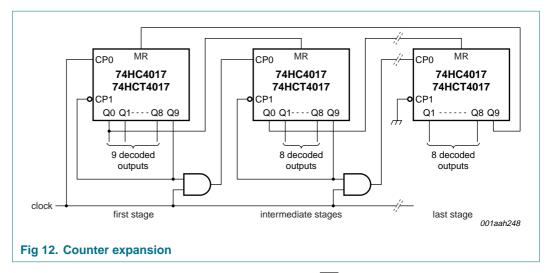
Туре	ype Input		Load		S1 position	S1 position			
	VI	t _r , t _f	CL	R _L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}		
74HC4017	V_{CC}	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}		
74HCT4017	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}		

12. Application information

Some examples of applications for the 74HC4017; 74HCT4017 are:

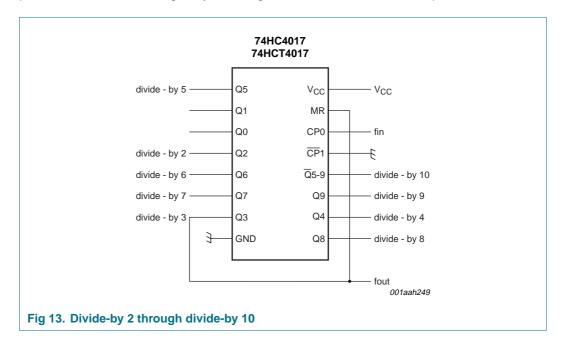
- Decade counter with decimal decoding
- 1 out of n decoding counter (when cascaded)
- Sequential controller
- Timer

<u>Figure 12</u> shows a technique for extending the number of decoded output states for the 74HC4017; 74HCT4017. Decoded outputs are sequential within each stage and from stage to stage, with no dead time (except propagation delay).



Remark: It is essential not to enable the counter on $\overline{CP1}$ when CP0 is HIGH, or on CP0 when $\overline{CP1}$ is LOW, as this would cause an extra count.

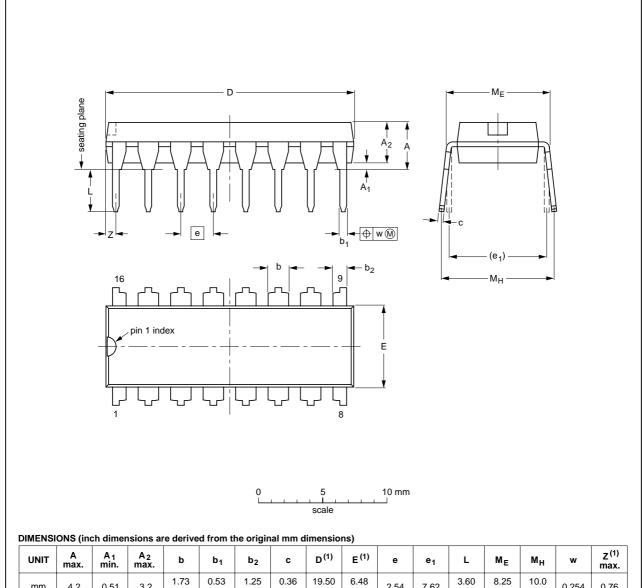
Figure 13 shows an example of a divide-by 2 through divide-by 10 circuit using one 74HC4017; 74HCT4017. Since the 74HC4017; 74HCT4017 has an asynchronous reset, the output pulse widths are narrow (minimum expected pulse width is 6 ns). The output pulse widths can be enlarged by inserting an RC network at the MR input.



13. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

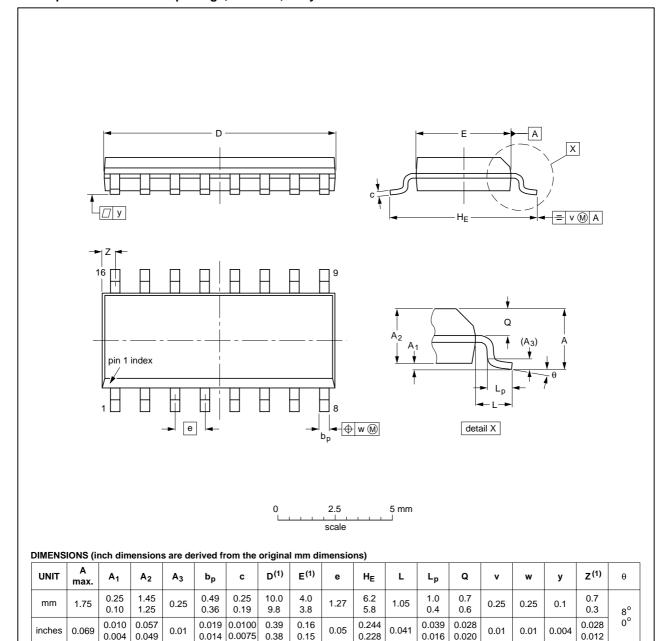
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT38-4						95-01-14 03-02-13	

Fig 14. Package outline SOT38-4 (DIP16)

74HC_HCT4017_3 © NXP B.V. 2008. All rights reserved.

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

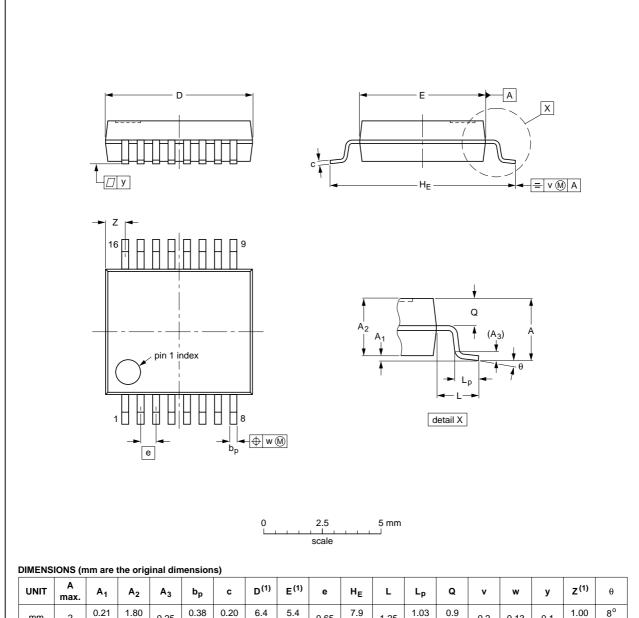
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE	
SOT109-1	076E07	MS-012				99-12-27 03-02-19	

Fig 15. Package outline SOT109-1 (SO16)

74HC_HCT4017_3 © NXP B.V. 2008. All rights reserved.

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



-				3			-,												
	UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
	mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

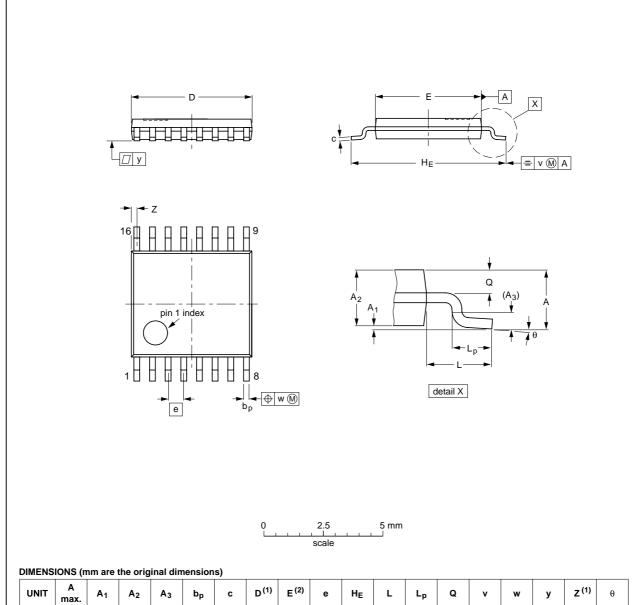
OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT338-1		MO-150			99-12-27 03-02-19	

Fig 16. Package outline SOT338-1 (SSOP16)

74HC_HCT4017_3 © NXP B.V. 2008. All rights reserved.

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



 						-,												
UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT403-1		MO-153			-99-12-27 03-02-18	

Fig 17. Package outline SOT403-1 (TSSOP16)

74HC_HCT4017_3 © NXP B.V. 2008. All rights reserved.

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

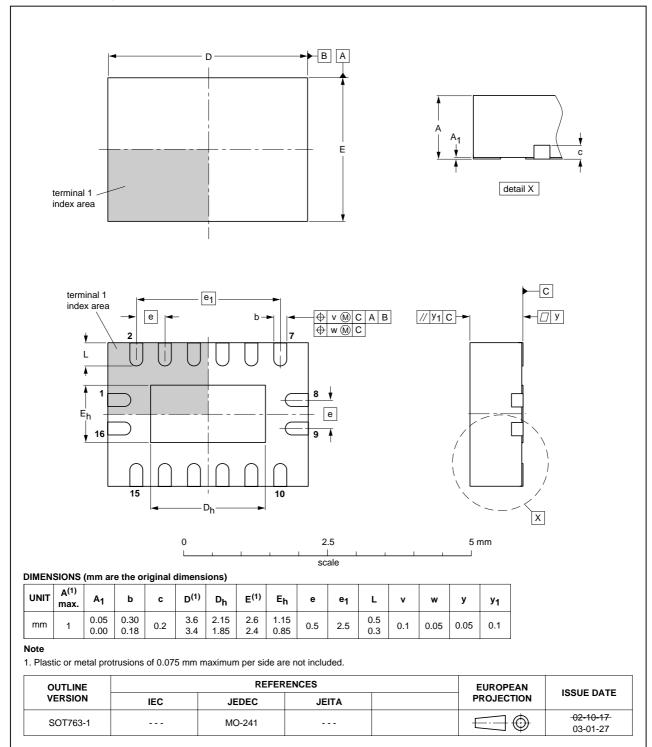


Fig 18. Package outline SOT763-1 (DHVQFN16)

74HC_HCT4017_3 © NXP B.V. 2008. All rights reserved.

14. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

15. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT4017_3	20080108	Product data sheet	-	74HC_HCT4017_CNV_2
Modifications:		of this data sheet has been of NXP Semiconductors.	redesigned to co	mply with the new identity
	 Legal texts 	have been adapted to the r	new company nam	e where appropriate.
	 Section 3: 0 	DHVQFN16 package added	l.	
	• Section 7: c	lerating values added for D	HVQFN16 packag	e.
	 Section 13: 	outline drawing added for [DHVQFN16 packa	ge.
74HC_HCT4017_CNV_2	19970829	Product specification	-	-

74HC4017; 74HCT4017

Johnson decade counter with 10 decoded outputs

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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